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Attorney's Docket No.: 07977/115003/US3251D1D1

2823



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Yamazaki, et al. Confirmation No.: 3966
Serial No.: 09/774,427 Art Unit : 2823
Filed : January 30, 2001 Examiner : W. David Coleman
Title : SEMICONDUCTOR DEVICES AND MANUFACTURING METHODS
THEREOF

Commissioner for Patents
Washington, D.C. 20231

AMENDMENT

Sir:

In response to the Official Action dated April 1, 2002,
Paper No. 7, in the above-referenced application, kindly amend
the above-identified application as follows.

In the Claims:

Claim 8 has been amended as follows.

8. (Amended) A semiconductor device having at least one
thin film transistor formed over a substrate, said thin film
transistor comprising:

a semiconductor layer having a source and drain regions and
a channel forming region therebetween;

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